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CM1218

Low Capacitance Transient Voltage Suppressors / ESD Protectors

Description

The CM1218 family of devices features transient voltage suppressor arrays that provide a very high level of protection for sensitive electronic components which may be subjected to electrostatic discharge (ESD).

All pins of the CM1218 are rated to withstand ± 15 kV ESD pulses using the IEC 61000-4-2 contact discharge method. Using the MIL-STD-883D (Method 3015) specification for Human Body Model (HBM) ESD, all pins are protected from contact discharges of greater than ± 30 kV.

The CM1218 is supplied in a number of compact, surface mount packages depending on the channel configuration desired.

Features

- Low I/O Capacitance at 7 pF Typical
- Two, Three, Four or Five Channels of ESD Protection
- In-system ESD Protection to ± 15 kV Contact Discharge, per the IEC 61000-4-2 International Standard
- Compact SMT Package Saves Board Space and Facilitates Layout in Space-critical Applications
- Each I/O Pin Can Withstand over 1000 ESD Strikes
- These are Pb-Free Devices

Applications

- High-speed Consumer Electronic Ports
- ESD Protection of PC Ports, Including USB Ports, Serial Ports, Parallel Ports, IEEE1394 Ports, Docking Ports, Proprietary Ports, etc.
- Protection of Interface Ports or IC Pins which are Exposed to High ESD Levels



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<http://onsemi.com>



SOT23-3
SO SUFFIX
CASE 419AH



SOT23-5
SO SUFFIX
CASE 527AH



SOT23-6
SO SUFFIX
CASE 527AJ



SOT143
SR SUFFIX
CASE 527AF



SOT-553
SE SUFFIX
CASE 463B



SOT-563
SE SUFFIX
CASE 463A



SC70-3
S7 SUFFIX
CASE 419AB



SC70-5
S7 SUFFIX
CASE 419AC

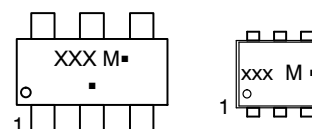


SC70-6
S7 SUFFIX
CASE 419AD

BLOCK DIAGRAMS

(see page 2)

MARKING DIAGRAM



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

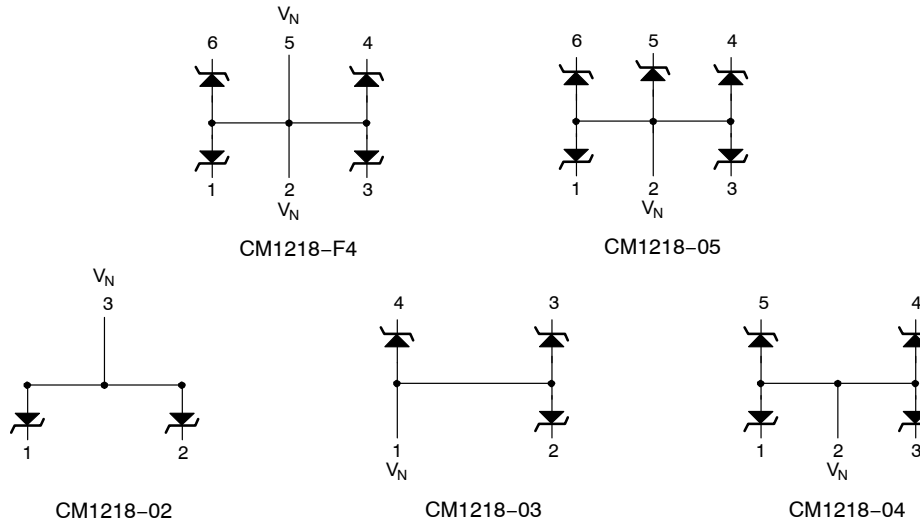
(Note: Microdot may be in either location)

ORDERING INFORMATION

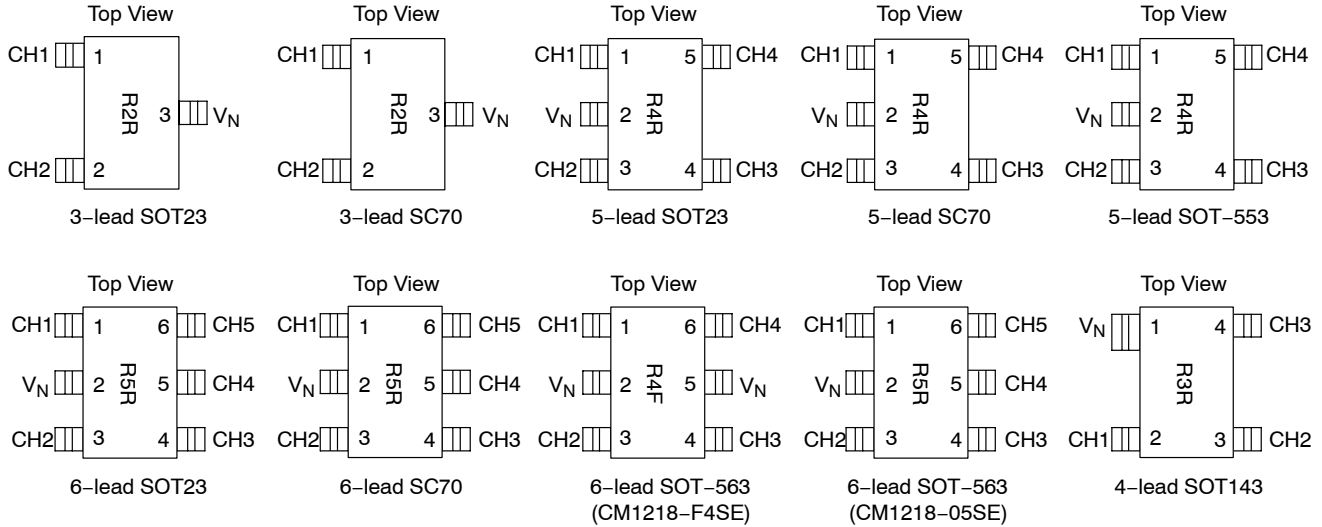
(see the last page of this document)

CM1218

BLOCK DIAGRAMS



PACKAGE / PINOUT DIAGRAMS & PIN DESCRIPTIONS



Rxx = Specific Device Code
 CHx = The Cathode of the Respective TVS Diode, which should be connected to the node requiring transient voltage protection
 V_N = The Anode of the TVS Diodes

Note: SOT23, SC70 and SOT143 and packages may differ in size. These drawings are not to scale.

Specifications

Table 1. ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Units
Storage Temperature Range	-65 to +150	°C
Package Power Dissipation SC70 SOT23-3, SOT23-5, SOT23-6, SOT143 SOT-553, SOT-563	0.2 0.225 0.15	W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 2. STANDARD OPERATING CONDITIONS

Parameter	Rating	Units
Operating Temperature	-40 to +85	°C

Table 3. ELECTRICAL OPERATING CHARACTERISTICS (Note 1)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
C_{IN}	Channel Input Capacitance	$T_A = 25^\circ\text{C}$, 2.5 VDC, 1 MHz		7		pF
ΔC_{IN}	Differential Channel I/O to GND Capacitance	$T_A = 25^\circ\text{C}$, 2.5 VDC, 1 MHz		0.19		pF
V_{RSO}	Reverse Stand-off Voltage	$I_R = 10\ \mu\text{A}$, $T_A = 25^\circ\text{C}$	5.5			V
		$I_R = 1\ \text{mA}$, $T_A = 25^\circ\text{C}$	6.1			V
I_{LEAK}	Leakage Current	$V_{IN} = 5.0\ \text{VDC}$, $T_A = 25^\circ\text{C}$			1	μA
V_{SIG}	Small Signal Clamp Voltage					
	Positive Clamp Negative Clamp	$I = 10\ \text{mA}$, $T_A = 25^\circ\text{C}$ $I = -10\ \text{mA}$, $T_A = 25^\circ\text{C}$		6.8 -0.8		V
V_{ESD}	ESD Withstand Voltage					
	Contact Discharge per IEC 61000-4-2 standard Human Body Model, MIL-STD-883, Method 3015	$T_A = 25^\circ\text{C}$; Notes 3 & 4 $T_A = 25^\circ\text{C}$; Notes 2 & 4	± 15 ± 30			kV
R_D	Diode Dynamic Resistance	$T_A = 25^\circ\text{C}$; Note 2				
	Forward Conduction			1.1		Ω
	Reverse Conduction			2.7		

1 All parameters specified at $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ unless otherwise noted.

2 Human Body Model per MIL-STD-883, Method 3015, $C_{Discharge} = 100\ \text{pF}$, $R_{Discharge} = 1.5\ \text{K}\Omega$, V_N grounded.

3 Standard IEC 61000-4-2 with $C_{Discharge} = 150\ \text{pF}$, $R_{Discharge} = 330\ \Omega$, V_N grounded.

4 These measurements performed with no external capacitor on CH_X .

Performance Information

Diode Capacitance

Typical diode capacitance with respect to positive TVS cathode voltage (reverse voltage across the diode) is given in Figure 1. Diode Capacitance vs. Reverse Voltage.

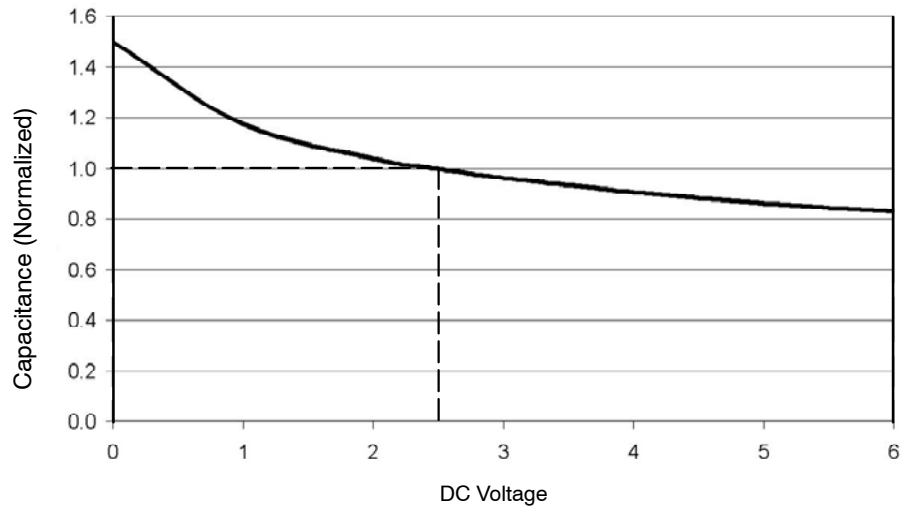
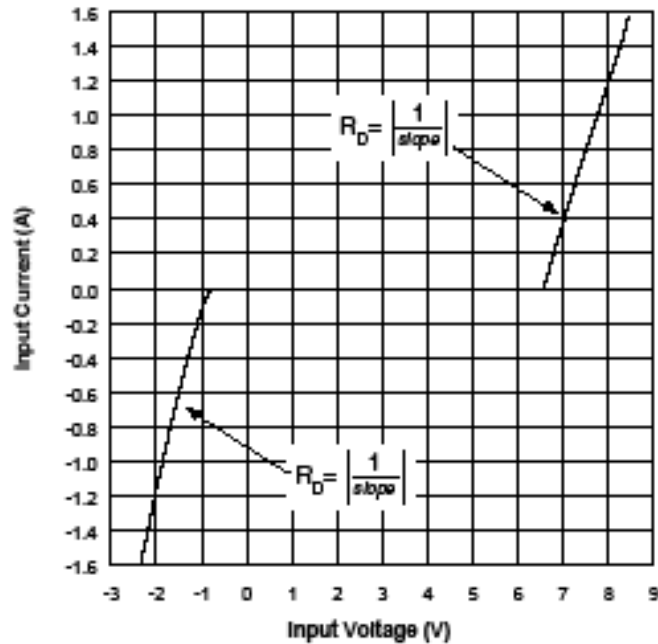


Figure 1. Diode Capacitance vs. Reverse Voltage

Typical High Current Diode Characteristics

Measurements are made in pulsed mode with a nominal pulse width of 0.7 ms.

Typical Input VI Characteristics
(Pulse-mode measurements, pulse width = 0.7ms nominal)



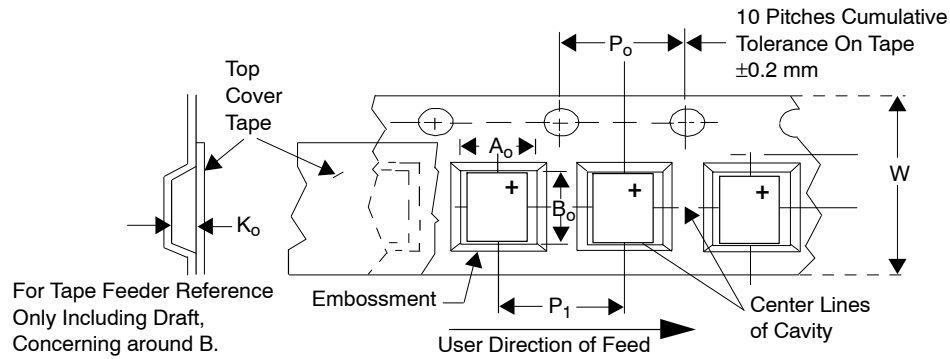
CM1218

Mechanical Details

The CM1218 devices are supplied in the following packages: SOT23-3, SOT23-5, SOT23-6, SOT143, SOT553, SOT563, SC70-3, SC70-5, and SC70-6.

Table 4. TAPE AND REEL SPECIFICATIONS

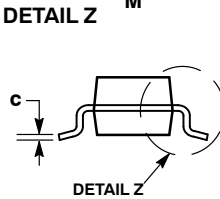
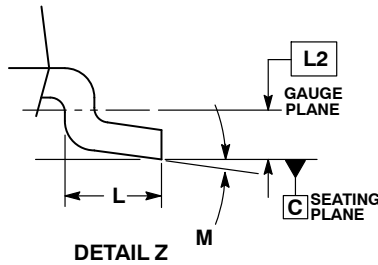
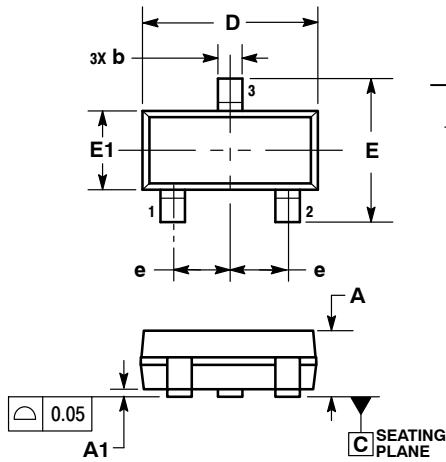
Part Number	Package	Package Size (mm)	Pocket Size (mm) $B_0 \times A_0 \times K_0$	Tape Width W	Reel Diameter	Qty per Reel	P_0	P_1
CM1218-02SO	SOT23-3	2.92 X 2.37 X 1.01	2.77 X 3.15 X 1.22	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1218-04SO	SOT23-5	2.90 X 2.80 X 1.45	3.20 X 3.20 X 1.40	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1218-05SO	SOT23-6	2.90 X 2.80 X 1.45	3.20 X 3.20 X 1.40	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1218-03SR	SOT143	2.92 X 2.37 X 1.01	2.60 X 3.15 X 1.20	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1218-04SE	SOT553	1.60 X 1.60 X 0.55	1.78 X 1.78 X 0.69	8 mm	178 mm (7")	5000	4 mm	4 mm
CM1218-F4SE CM1218-05SE	SOT563	1.60 X 1.60 X 0.55	1.78 X 1.78 X 0.69	8 mm	178 mm (7")	5000	4 mm	4 mm
CM1218-02S7	SC70-3	2.05 X 1.25 X 0.95	2.40 X 2.40 X 1.19	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1218-04S7	SC70-5	2.05 X 1.25 X 0.95	2.25 X 2.40 X 1.20	8 mm	178 mm (7")	3000	4 mm	4 mm
CM1218-05S7	SC70-6	2.05 X 1.25 X 0.95	2.25 X 2.40 X 1.20	8 mm	178 mm (7")	3000	4 mm	4 mm



CM1218

PACKAGE DIMENSIONS

SOT-23 3-Lead (TO-236AA) CASE 419AH-01 ISSUE O

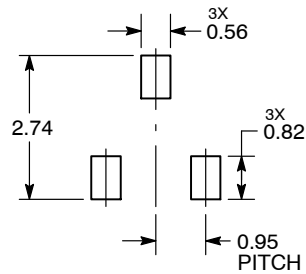


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

DIM	MILLIMETERS	
	MIN	MAX
A	0.75	1.17
A1	0.05	0.15
b	0.30	0.50
c	0.08	0.20
D	2.80	3.05
E	2.10	2.64
E1	1.20	1.40
e	0.95 BSC	
L	0.40	0.60
L2	0.25 BSC	
M	0°	8°

RECOMMENDED SOLDERING FOOTPRINT*



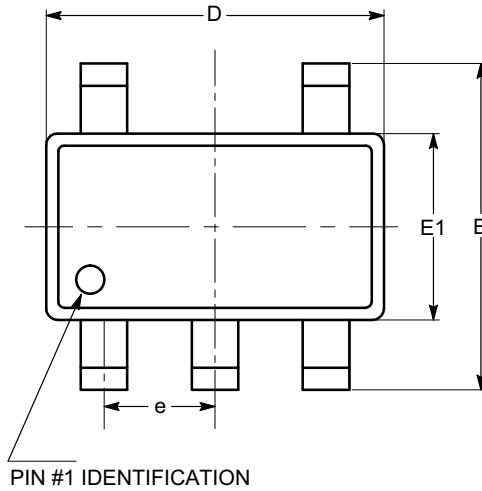
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

CM1218

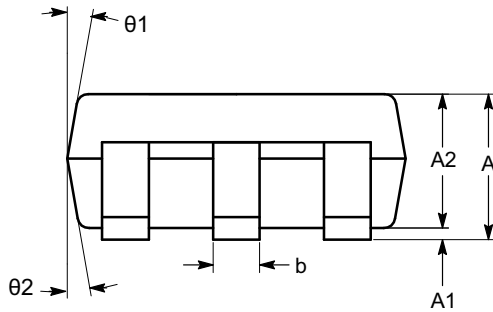
PACKAGE DIMENSIONS

SOT-23, 5 Lead
CASE 527AH-01
ISSUE O

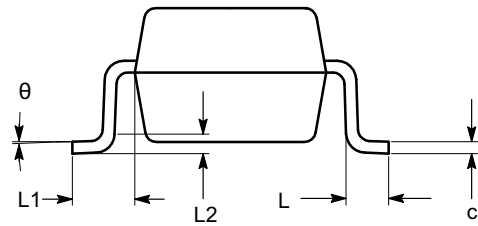


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	0.90		1.45
A1	0.00		0.15
A2	0.90	1.15	1.30
b	0.30		0.50
c	0.08		0.22
D	2.90 BSC		
E	2.80 BSC		
E1	1.60 BSC		
e	0.95 BSC		
L	0.30	0.45	0.60
L1	0.60 REF		
L2	0.25 REF		
θ	0°	4°	8°
$\theta 1$	5°	10°	15°
$\theta 2$	5°	10°	15°



SIDE VIEW



END VIEW

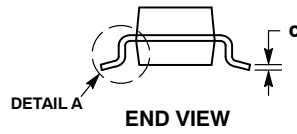
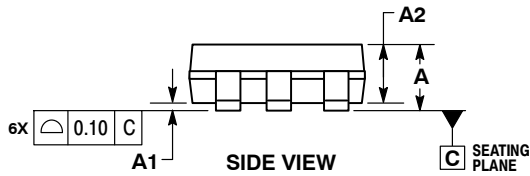
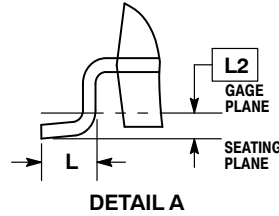
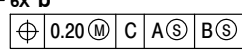
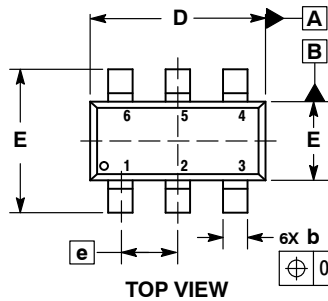
Notes:

- (1) All dimensions in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard MO-178.

CM1218

PACKAGE DIMENSIONS

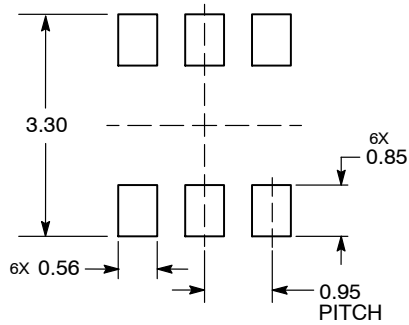
SOT-23, 6 Lead
CASE 527AJ-01
ISSUE A



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DATUM C IS THE SEATING PLANE.

MILLIMETERS		
DIM	MIN	MAX
A	---	1.45
A1	0.00	0.15
A2	0.90	1.30
b	0.20	0.50
c	0.08	0.26
D	2.70	3.00
E	2.50	3.10
E1	1.30	1.80
e	0.95 BSC	
L	0.20	0.60
L2	0.25 BSC	

RECOMMENDED SOLDERING FOOTPRINT*



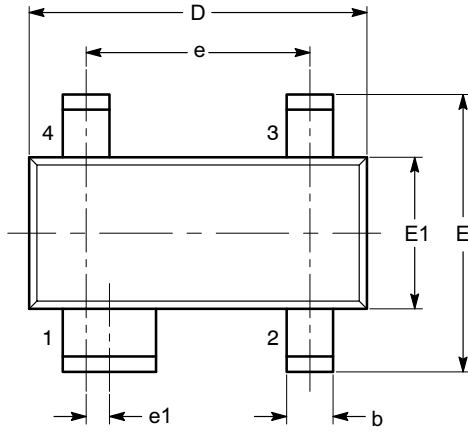
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

CM1218

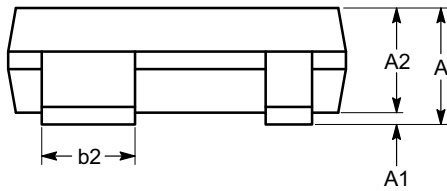
PACKAGE DIMENSIONS

SOT-143, 4 Lead
CASE 527AF-01
ISSUE A

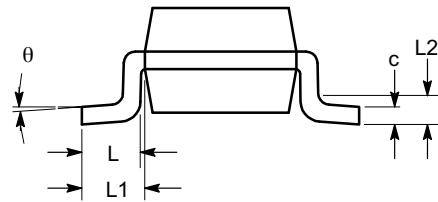


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	0.80		1.22
A1	0.05		0.15
A2	0.75	0.90	1.07
b	0.30		0.50
b2	0.76		0.89
c	0.08		0.20
D	2.80	2.90	3.04
E	2.10		2.64
E1	1.20	1.30	1.40
e	1.92 BSC		
e1	0.20 BSC		
L	0.40	0.50	0.60
L1	0.54 REF		
L2		0.25	
θ	0°		8°



SIDE VIEW

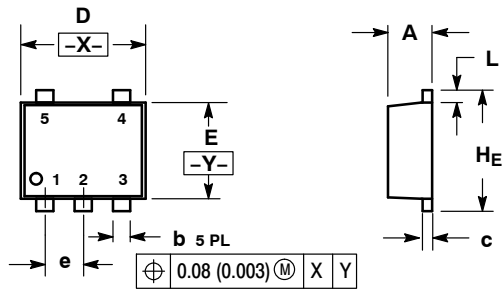


END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC TO-253.

PACKAGE DIMENSIONS

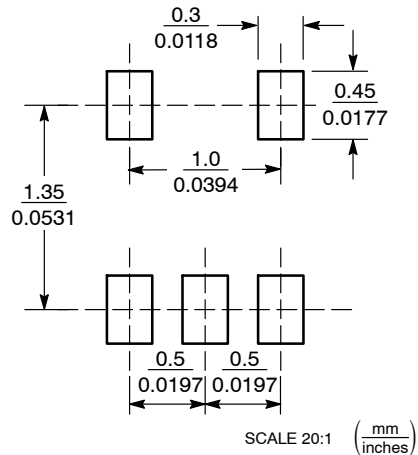
SOT-553, 5 LEAD
CASE 463B-01
ISSUE B

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
c	0.08	0.13	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.063	0.067
E	1.10	1.20	1.30	0.043	0.047	0.051
e	0.50 BSC			0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
H _E	1.50	1.60	1.70	0.059	0.063	0.067

SOLDERING FOOTPRINT*



SCALE 20:1 (mm/inches)

STYLE 2:

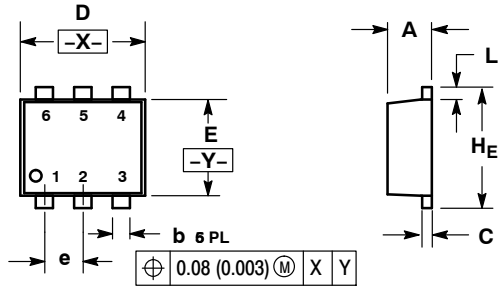
- PIN 1: CATHODE
 2. COMMON ANODE
 3. CATHODE 2
 4. CATHODE 3
 5. CATHODE 4

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

CM1218

PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A-01 ISSUE F



NOTES:

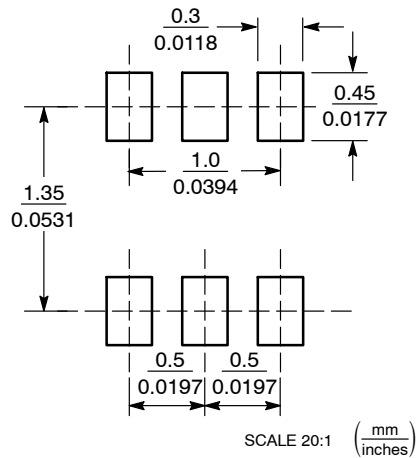
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
C	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
E	1.10	1.20	1.30	0.043	0.047	0.051
e	0.5 BSC			0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
H _E	1.50	1.60	1.70	0.059	0.062	0.066

STYLE 7:

- PIN 1: CATHODE
 2: ANODE
 3: CATHODE
 4: CATHODE
 5: ANODE
 6: CATHODE

SOLDERING FOOTPRINT*

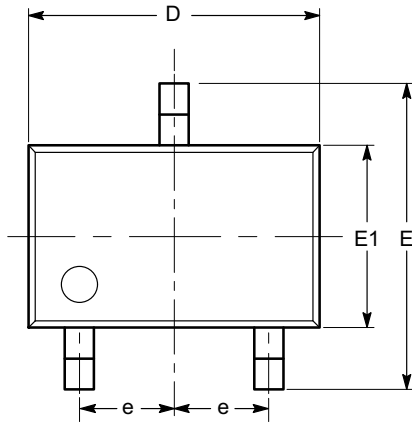


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CM1218

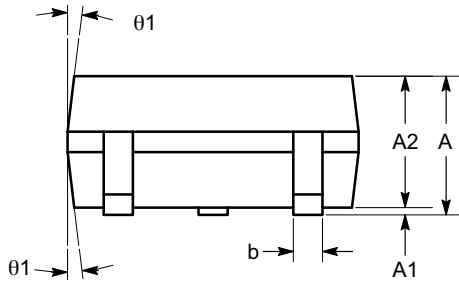
PACKAGE DIMENSIONS

SC-70, 3 Lead, 1.25x2
CASE 419AB-01
ISSUE O

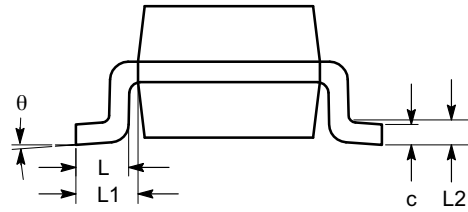


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	0.80		1.10
A1	0.00		0.10
A2	0.80	0.90	1.00
b	0.15		0.30
c	0.08		0.22
D	1.80	2.00	2.20
E	1.80	2.10	2.40
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.26	0.36	0.46
L1	0.42 REF		
L2	0.15 BSC		
θ	0°		8°
$\theta 1$	4°		10°



SIDE VIEW



END VIEW

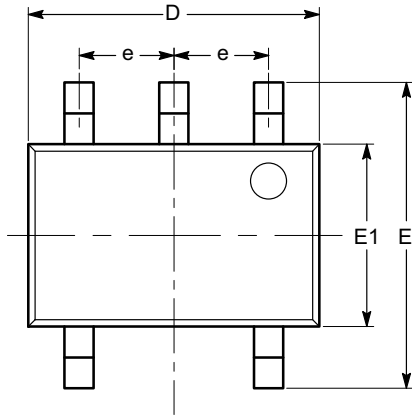
Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-203.

CM1218

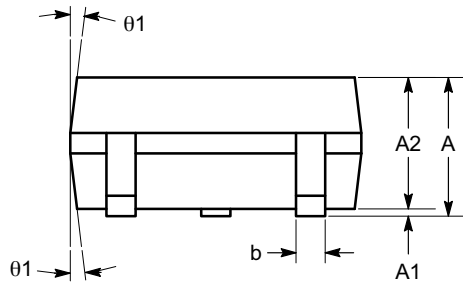
PACKAGE DIMENSIONS

SC-88A (SC-70 5 Lead), 1.25x2
CASE 419AC-01
ISSUE A

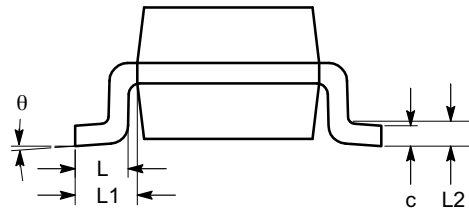


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	0.80		1.10
A1	0.00		0.10
A2	0.80		1.00
b	0.15		0.30
c	0.10		0.18
D	1.80	2.00	2.20
E	1.80	2.10	2.40
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.26	0.36	0.46
L1	0.42 REF		
L2	0.15 BSC		
θ	0°		8°
$\theta 1$	4°		10°



SIDE VIEW



END VIEW

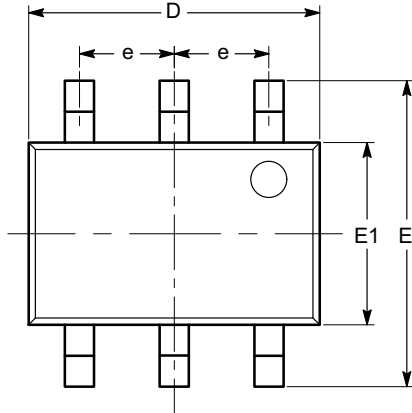
Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-203.

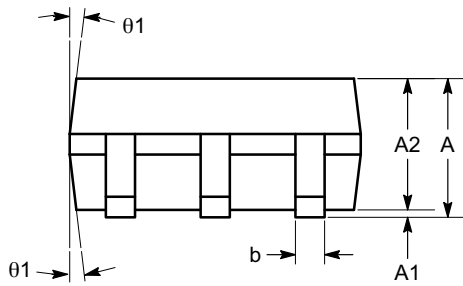
CM1218

PACKAGE DIMENSIONS

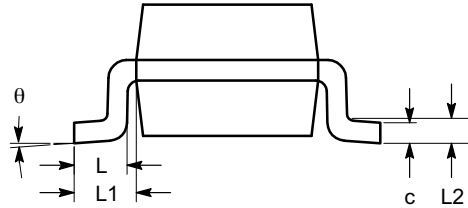
SC-88 (SC-70 6 Lead), 1.25x2
CASE 419AD-01
ISSUE A



TOP VIEW



SIDE VIEW



END VIEW

SYMBOL	MIN	NOM	MAX
A	0.80		1.10
A1	0.00		0.10
A2	0.80		1.00
b	0.15		0.30
c	0.10		0.18
D	1.80	2.00	2.20
E	1.80	2.10	2.40
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.26	0.36	0.46
L1	0.42 REF		
L2	0.15 BSC		
θ	0°		8°
θ1	4°		10°

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-203.

CM1218

ORDERING INFORMATION

Device	Package	Shipping
CM1218-02SO	SOT23-3 (Pb-Free)	3000/Tape & Reel
CM1218-04SO	SOT23-5 (Pb-Free)	3000/Tape & Reel
CM1218-05SO	SOT23-6 (Pb-Free)	3000/Tape & Reel
CM1218-03SR	SOT-143 (Pb-Free)	3000/Tape & Reel
CM1218-04SE	SOT-553 (Pb-Free)	5000/Tape & Reel

ORDERING INFORMATION (cont'd)

Device	Package	Shipping
CM1218-05SE	SOT563 (Pb-Free)	5000/Tape & Reel
CM1218-F4SE	SOT563 (Pb-Free)	5000/Tape & Reel
CM1218-02S7	SC70-3 (Pb-Free)	3000/Tape & Reel
CM1218-04S7	SC70-5 (Pb-Free)	3000/Tape & Reel
CM1218-05S7	SC70-6 (Pb-Free)	3000/Tape & Reel

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